

# IoT off-line isolated power supply 3 W 5 V, <13 mW standby

SMPS based on CoolSET™ ICE3RBR4765JG current mode controller

### About this document

#### Scope and purpose

This document presents one solution for a simple, low-power, offline flyback converter based on the Infineon ICE3RBR4765JG controller. It is an engineering report of features and performance for a 5 V 3 W solution, with explanations covering component selection, circuit and layout design.

The ICE3RBR4765JG is an offline SMPS current mode controller from the CoolSET™ jitter series, with integrated 650 V CoolMOS™ MOSFETs and a startup cell.

#### Intended audience

This document is intended for power supply design engineers, application engineers, students, etc., who wish to design low cost, highly reliable off-line Switched Mode Power Supply (SMPS) systems for:

- Applications related to the Internet of things (IoT)
  - 1) Standby power supply
  - 2) Power supply for microcontrollers
  - 3) Power supply for standalone sensors operating on a wired/wireless interface bus
- USB-power supply embedded in a wall plug
- Intelligent wall plug switched by wireless (with relay)
- Metering application
- General Applications with small formfactor in the power range 1 W to 3 W.



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Introduction

#### Introduction 1

This is an engineering report for a 5 V, 3 W offline flyback power supply. This document contains the technical specification for the power supply, a list/description of the main features, circuit and layout description as well as the measurement results.

In this application, an Infineon ICE3RBR4765JG from the CoolSET™ jitter series is used as a flyback controller. The controller has a built-in 650 V CoolMOS™ as the main switching component, as well as the startup cell. The reference design board operates in Discontinuous Conduction Mode (DCM), running at 65 kHz switching frequency. The output is a single 5 V / 600 mA, generated by secondary side regulation. Active Burst Mode (ABM) operation provides very low standby power consumption (less than 13 mW over input voltage range 180 Vac ~ 265V<sub>ac</sub>). Low EMI is achieved by built-in frequency jitter and soft start operation.



Figure 1 Top and bottom side of the reference design board



**Technical specification** 

## 2 Technical specification

## Table 1 Power supply technical specification

Input voltage	180 V <sub>ac</sub> ~265 V <sub>ac</sub>
Line frequency	50 Hz, 60 Hz
Output voltage	5 V ±5%
Rated output current	600 mA
Rated output power	3 W
Efficiency	79% @ 230 V <sub>ac</sub> , full load
Output voltage ripple (max.)	<80 mVpp
No load power consumption @Vin: 180Vac ~ 265Vac	<13 mW
Power consumption at 10 mA load	<100 mW
Device dimensions	50 mm x 23.5 mm x 14 mm (L x W x H)
Isolation	Reinforced isolation between primary and secondary side



List of product features – ICE3RBR4765JG

#### List of product features – ICE3RBR4765JG 3

Table 2	List of features		
650 V avalar	nche rugged CoolMOS™ with built-in startup cell		
Active Burst	: Mode (ABM) for lowest standby power		
65 kHz inter	65 kHz internally fixed switching frequency		
Auto restart	Auto restart protection mode for overload, open loop, V <sub>cc</sub> undervoltage, overtemperature and V <sub>cc</sub>		
overvoltage			
Built-in soft start			
Fast load jump response in Active Burst Mode (ABM)			
Internal PWM leading edge blanking			
Built-in frequency jitter feature and soft driving for low EMI			
BiCMOS technology provides wide V <sub>cc</sub> range			



Circuit description

#### Circuit description 4

#### 4.1 Circuit diagram

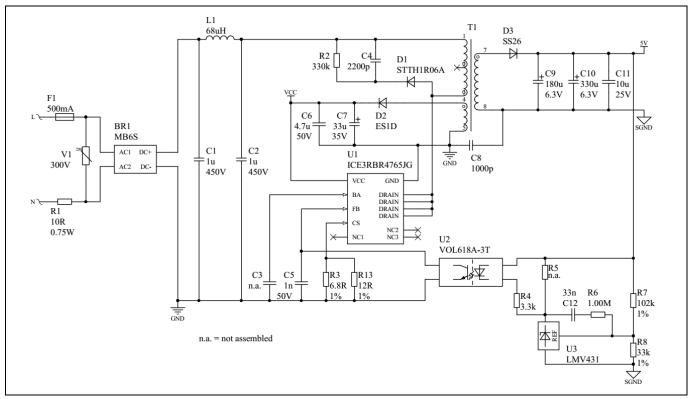


Figure 2 Schematic diagram for 5 V, 3 W power supply

#### 4.2 Introduction

Key features of this application are the circuit simplicity, very small form factor and very low no-load power consumption, with regard to the performance and stable operation in all conditions. In order to fit into a very small form factor, the larger components are selected based on a maximum height as well as having the smallest PCB footprint. The very low power consumption with no-load is achieved by addressing critical components that continuously draw power, as well as the controller power consumption that depends significantly on its supply voltage.

#### 4.3 Line input rectification

The input voltage range is 180 V<sub>ac</sub>~265 V<sub>ac</sub>, and the converter is supplied by two wires without a protective ground connection. This application does not cover the low input voltage range from 85 V<sub>ac</sub>, mainly due to the need for a large bulk capacitor in the primary side.

Line input rectification circuit contains the fuse F1, the series resistor R1, the varistor V1 and the standard bridge rectifier BR1. F1 is a slow blow 500 mA fuse in a radial case. The varistor is used as a surge and overvoltage protector. Resistor R1 limits the inrush current and reduces the EMI.

#### 4.4 Primary side EMI filter

The rectified input voltage is filtered by capacitors C1 and C2. L1 is the EMI suppressor for any high frequency spikes in the primary current. Capacitors C1 and C2 are ceramic 1uF 450 V devices in an SMD package, selected



Circuit description

particularly for the small package size. With an input voltage of 180 V<sub>ac</sub> and a full load, C1 and C2 will discharge to approximately 180 V. The maximum value of the rectified voltage is 375 V for a 265 V<sub>ac</sub> input.

#### 4.5 Primary side snubber

When the CoolMOS™ MOSFET turns off, a high drain voltage spike occurs - caused by the transformer leakage inductance. These oscillations are damped by the RC snubber. D1 is a high voltage ultrafast diode with a very short recovery time. C4 is selected based on the oscillation period and the voltage overshoot on the CoolMOS™ MOSFET drain. R2's value and its power rating depend on the maximum peak current through the primary inductance and the CoolMOS™ MOSFET voltage overshoot. The design margin for the CoolMOS™ MOSFET drain to source voltage must be maintained at all operating points. The snubber also suppresses radiated EMI.

#### 4.6 Power supply for CoolSET™ controller

When the input voltage is applied, the IC starts to charge its V<sub>CC</sub> capacitor through the built-in startup cell. The startup cell is activated if the V<sub>CC</sub> voltage is below the undervoltage threshold level of 10.5 V. V<sub>CC</sub> charge current is controlled to 0.9 mA by the startup cell. The startup cell remains active until the Vcc voltage exceeds the onthreshold of 18 V, when the chip starts to operate and the startup cell is turned off. By implementing hysteresis for the startup V<sub>cc</sub> voltage, an uncontrolled ringing when switching on is avoided.

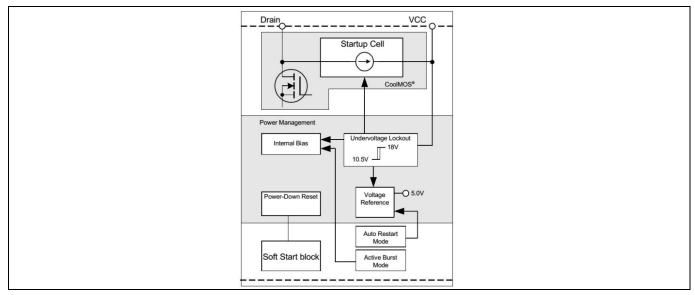


Figure 3 Power management of the IC

In order to achieve the lowest power consumption, V<sub>cc</sub> is set as low as possible within a defined range. Due to the tolerance of the IC, especially the undervoltage lockout level (which can be as high as 11.2 V), a safe margin for V<sub>CC</sub> is taken into account when the transformer auxiliary winding is determined. Capacitors C6 and C7 are selected to be sufficient to keep V<sub>cc</sub> above this safe margin during the discharge phase, when the IC is not in a steady state. The V<sub>cc</sub> capacitance must not be unnecessarily large with respect to the startup time. In steady state conditions  $V_{cc}$  is stable as the IC is supplied from the auxiliary winding.

#### 4.7 Secondary side rectification

The secondary side rectification circuit is a simple diode rectifier with filter capacitors. Diode D3 is a Schottky type, selected to meet the current and reverse voltage requirements. Its low forward voltage reduces the power loss in D3, and therefore lowers its temperature and improves the overall efficiency.



#### Circuit description

Selection of output capacitors C9 and C10 directly affects the output voltage ripple, standby power consumption and the repetition time period during active burst mode. In general, large output capacitors reduce the output voltage ripple and increase the repetition time period which, in turn, reduces the standby power consumption. However, too large an output capacitance leads to a very slow V<sub>out</sub> discharge at extremely light load or open load. If V<sub>CC</sub> discharges and triggers the UVLO before the IC enters active burst mode, the IC may be trapped in an endless auto restart mode and never enters active burst mode.

The output voltage ripple is reduced by selecting an ultra low-ESR capacitor. Typically, capacitors with ultra low ESR have relatively high leakage current that increases standby power consumption significantly. By combining one ultra low-ESR capacitor and one regular capacitor, maximum output voltage ripple is less than 80 mVpp and the standby power consumption is less than 13 mW.

#### 4.8 Feedback loop circuit

The major requirement for the feedback loop is to match the dynamically varying load and provide stable system control. The output voltage is sensed using an LMV431 precision shunt regulator (1% initial tolerance, 1.24 V reference voltage), which has a low operating current (55 μA). Resistors R7 and R8 set the output voltage to 5 V. The resistance of R7 and R8 should be selected to be as large as possible to reduce the standby power consumption while not being so large that they affect control stability. R4 determines the optocoupler (U2) diode current - this is important for fast transient response and as well for standby power consumption. Optocoupler U2 is selected based on its Current Transfer Ratio (CTR) and low input current while ensuring the package permits a suitable creepage distance.

In terms of component selection, the feedback loop circuitry is the most complicated to calculate as the open load power consumption must be very low. Additionally, output voltage regulation, load transient response, stability, output voltage ripple and burst mode repetition time depend on the feedback loop. Therefore, most component values in the feedback loop are determined by testing.



CoolSET™ ICE3RBR4765JG controller

#### 5 CoolSET™ ICE3RBR4765JG controller

The ICE3RBR4765JG controller belongs to the CoolSET™ jitter series and includes built-in features for soft start, blanking window, frequency jitter, active burst mode, propagation delay compensation, modulated gate driving and auto-restart when protection features are triggered.

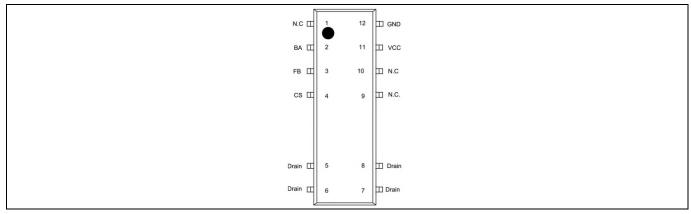


Figure 4 Pin configuration PG-DSO-12

For full details about the ICE3RBR4765JG controller, see [1].

#### 5.1 Start up

The built-in startup cell is sufficient for the ICE3RBR4765JG to start without external startup resistors. The startup cell connects the drain pin to the V<sub>CC</sub> pin of the IC and charges the external capacitors to 18 V when the IC starts switching. At this point, the V<sub>CC</sub> pin is supplied from the auxiliary winding.

In the startup phase, the IC provides a soft start function to gradually increase the primary current by increasing the duty cycle in 32 steps. The soft start phase finishes 20 ms after the IC is switched on ( $V_{cc}$  exceeds 18 V).

In addition to start up, the soft start function is also activated at a restart attempt during auto restart. This means that the converter transfers a significant amount of energy to the secondary side every time the IC restarts. As a consequence, when the output is open and the input voltage is interrupted significant output voltage overshoot can occur if the feedback loop response is not sufficiently fast, as the converter is charging the output capacitors even though the output voltage is close to V<sub>out</sub> nominal.

#### 5.2 Peak primary current control

The primary current is sensed by the external shunt resistors, R3 and R13. This signal is amplified and then compared with the feedback signal for cycle by cycle peak current limit operation. If the amplified current sense signal exceeds the feedback signal, the on-time Ton of the driver is closed.

Resistors R3 and R13 determine the maximum peak current of the integrated CoolMOS™ MOSFET and, as a result, the maximum output power is limited. Overload protection is triggered if the current sense voltage exceeds the threshold  $V_{csth}$ =1.03 V. Integrated propagation delay compensation reduces the influence of the AC input voltage on the maximum output power. Leading edge blanking is integrated to protect the current limit from distortions caused by leading edge spikes.



CoolSET™ ICE3RBR4765JG controller

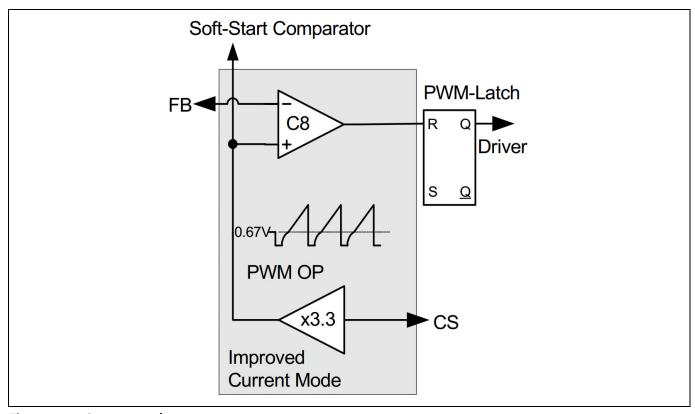


Figure 5 **Current mode** 

In active burst mode, the peak primary current limit is reduced to V<sub>cs</sub>=0.34 V. Thus, the conduction loss and audible noise is reduced.

#### 5.3 **Active Burst Mode (ABM)**

The system enters ABM under low load conditions. With ABM, the efficiency increases significantly at light load while still maintaining a low ripple on V<sub>OUT</sub> and a fast response on step changes in load. The significant feature is the extremely low standby power consumption: <13 mW at 180 V<sub>ac</sub>~265 V<sub>ac</sub>.

The system will enter ABM if the feedback signal falls and remains below 1.35 V for the 20 ms blanking time. This time window prevents ABM being entered due to large step changes in load. When ABM is entered, the current consumption of the IC is reduced to approximately 450  $\mu A$ . During ABM,  $V_{CC}$  must be kept above the undervoltage lockout level of 10.5 V to prevent the startup cell from switching on and the IC from restarting. The feedback signal is a sawtooth between 3.5 V when the IC starts switching and 3.0 V when the IC stops switching. The feedback signal will increase immediately if there is a step change in load. The system will exit the ABM when the feedback signal exceeds 4.0 V.

#### Protection modes and auto restart 5.4

The IC provides an auto restart mode as a protection feature to prevent damage of the device. Table 3 shows possible system failures, conditions and corresponding protection modes.



CoolSET™ ICE3RBR4765JG controller

Table 3 System failures and protection modes

Protection function	Failure condition	Protection mode
V <sub>cc</sub> overvoltage	1. $V_{VCC}$ > 20.5 V & FB > 4 V & during soft start period & last for 30 $\mu$ s 2. $V_{VCC}$ > 25.5 V & last for (120+30) $\mu$ s (inactive during burst mode)	Auto restart
Overtemperature (controller junction)	T <sub>J</sub> > 140°C & last for 30 μs	Auto restart
Overload/open loop	$V_{FB}$ > 4 V & last for 20 ms & $V_{BA}$ > 4.0 V & last for 30 μs (extended blanking time counted from charging $V_{BA}$ from 0.9 V to 4.0 V)	Auto restart
V <sub>cc</sub> Undervoltage/short optocoupler	$V_{VCC}$ < 10.5 V & last for 10 ms + 30 $\mu$ s	Auto restart
Auto restart enable	V <sub>BA</sub> < 0.33 V & last for 30 μs	Auto restart

When the system enters the auto restart mode, the IC will be off. At this point switching stops and Vcc starts to drop. When V<sub>CC</sub> reaches the turn-off threshold of 10.5 V, the startup cell will turn on and start to charge V<sub>CC</sub> up to the turn-on threshold of 18 V, allowing the IC to turn on again. After the startup phase, if the fault condition still exists, the IC will enter auto restart mode once again, otherwise the system will resume normal operation.



**PCB Layout** 

#### **PCB Layout** 6

The printed circuit board (PCB) is dual layer, double sided, and manufactured with the standard 1.5 mm thickness and 1oz copper. Between the primary and secondary side, the creepage distance is created according to requirements for reinforced isolation. The overall PCB size is 50 mm x 23.5 mm.

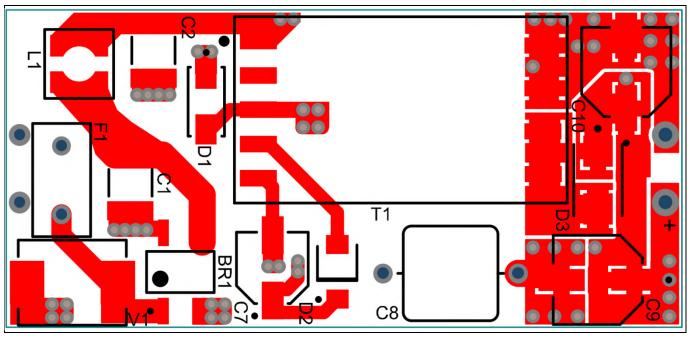


Figure 6 Layout top

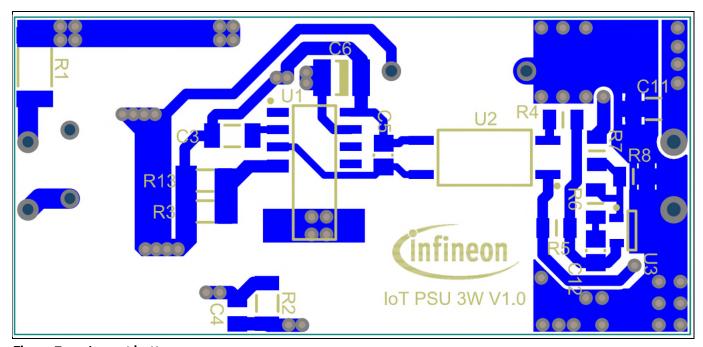


Figure 7 Layout bottom



Bill of materials

#### Bill of materials 7

#### Table 4 **Bill of materials**

Component designator	Description	Manufacturer	Manufacturer part number
BR1	Bridge rectifier, 600 V, 0.5 A, TO-269AA	Vishay	MB6S-E3/45
C1, C2	Capacitor ceramic, 1 μF, 450 V, 1812	TDK	CKG45NX7T2W105M500JH
C4	Capacitor ceramic, 2200 pF, 250V, 0805	Murata	GRJ21AR72E222KWJ1D
C5	Capacitor ceramic, 1 nF, 50 V, 0805		standard capacitor
C6	Capacitor ceramic, 4.7 μF, 50 V, 1206		standard capacitor
C7	Capacitor electrolytic, 33 μF, 35 V, SMD	Panasonic	EEE-FT1V330AR
C8	Capacitor ceramic, 1000 pF, 250 V, X1/Y1	Murata	DE1E3KX102MA4BN01F
C9	Capacitor electrolytic, 180 μF, 6.3 V, SMD	Würth Elektronik	875105144007
C10	Capacitor electrolytic, 330 μF, 6.3 V, SMD	Panasonic	EEEFT0J331AP
C11	Capacitor ceramic, 10 μF, 25 V, 1206	Würth Elektronik	885012108021
C12	Capacitor ceramic, 33 nF, 50 V, 0805		standard capacitor
D1	Diode ultrafast, 600 V, 1 A, DO-214AC	STMicroelectronics	STTH1R06A
D2	Diode ultrafast, 200 V, 1 A, DO-214AC	Fairchild	ES1D
D3	Diode Schottky, 60 V, 2 A, DO-214AA	Vishay	SS26-E3/52T
F1	Fuse slow blow, 250 V, 0.5 A, TH	Multicomp	MST 500MA 250V
L1	Inductor, 68μH, 320mA, 3816	Würth Elektronik	744031680
R1	Resistor, 10 Ω, 300 V, 2010	Vishay	CRCW201010R0FKEF
R2	Resistor, 330 k $\Omega$ , 200 V, 1%, 1206		standard resistor
R3	Resistor, 6.8 Ω, 1%, 1206		standard resistor
R4	Resistor, 3.3 kΩ, 1%, 0805		standard resistor
R6	Resistor, 1 MΩ, 1%, 0805		standard resistor
R7	Resistor, 102 k $\Omega$ , 1%, 0805		standard resistor
R8	Resistor, 33 kΩ, 1%, 0805		standard resistor
R13	Resistor, 12 Ω, 1%, 1206		standard resistor
TR1	Transformer, 2.2 mH, EE13/7/4	Würth Elektronik	750817018
U1	IC, ICE3RBR4765JG, PG-DSO-12	Infineon	ICE3RBR4765JG
U2	Optocoupler, VOL618A, LSOP 4	Vishay	VOL618A-3X001T
U3	IC, LMV431, SOT-23-3	Texas Instruments	LMV431AIMF/NOPB
V1	Varistor, CU3225K300G2	Epcos	B72650M0301K072



**Transformer specification** 

#### **Transformer specification** 8

#### **Electrical diagram** 8.1

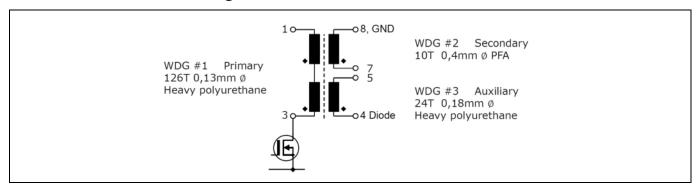


Figure 8 Transformer electrical diagram

#### **Electrical specification** 8.2

Table 5 Transformer electrical specification

Primary inductance	Pins 1-3, measured when all other windings are open	2.2 mH
Number of primary turns	Pins 1-3	126
Number of secondary turns	Pins 7-8	10
Number of auxiliary turns	Pins 4-5	24

#### 8.3 Material

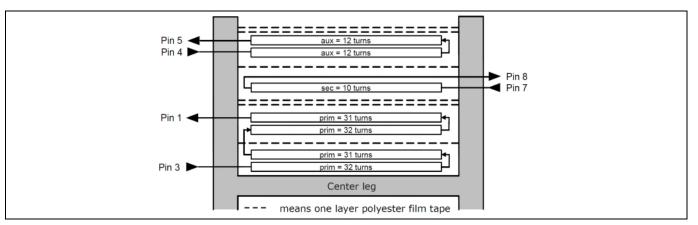
Table 6 **Transformer material** 

Core	EE13/7/4, N87 material, air gap 0.099 mm
Coil former	EE13/7/4, SMD 9 pins, for reinforced insulation
Wire for primary winding	0.13 mm dia., heavy polyurethane insulated wire
Wire for secondary winding	0.4 mm dia., PFA insulated wire
Wire for auxiliary winding	0.18 mm dia., heavy polyurethane insulated wire
Insulation tape	Polyester film tape



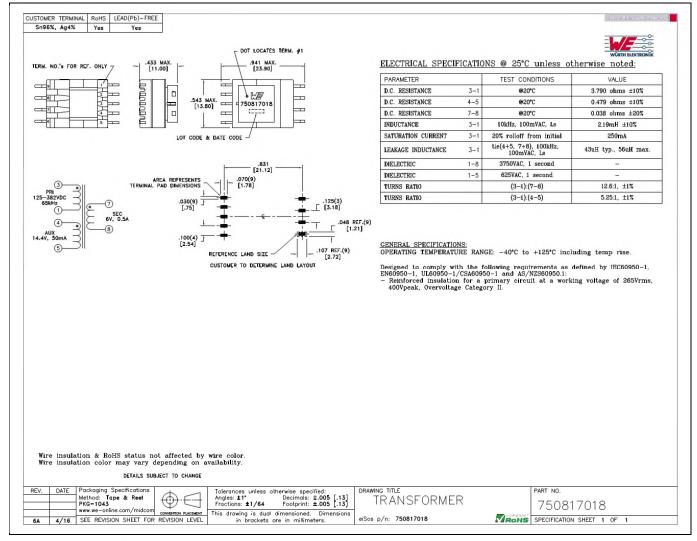
**Transformer specification** 

#### Transformer build diagram 8.4



Transformer build diagram Figure 9

#### Transformer design by Würth Elektronik 8.5



Transformer design by Würth Elektronik Figure 10



## 9 Test results

## 9.1 Efficiency

Efficiency measurements are performed at room temperature in steady state. The line frequency is 50 Hz.

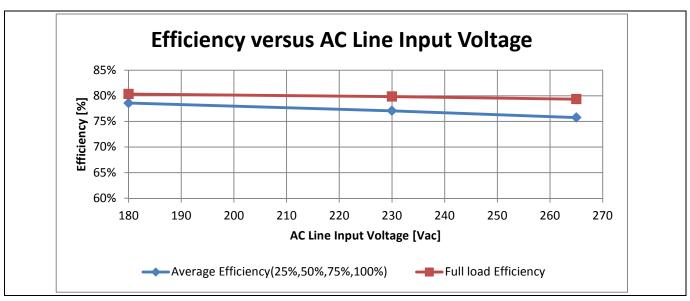


Figure 11 Efficiency versus input voltage

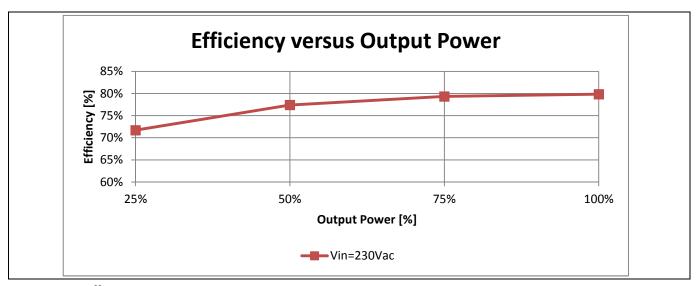


Figure 12 Efficiency versus output power



## 9.2 No-load power consumption

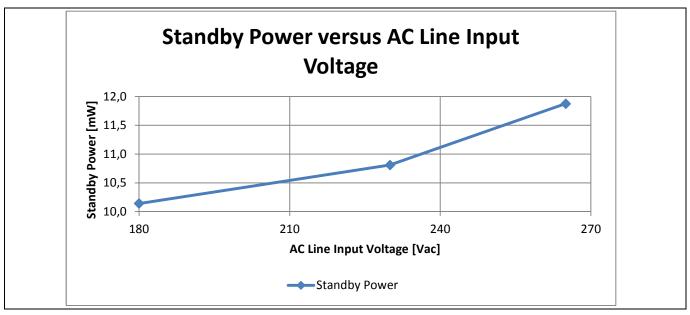


Figure 13 No-load input power consumption versus input voltage

Power consumption without load is measured with the power analyzer YOKOGAWA WT3000, using the integration function for the duration of one minute.

## 9.3 Light load power consumption

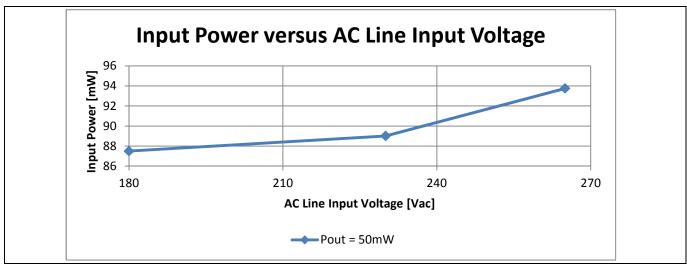
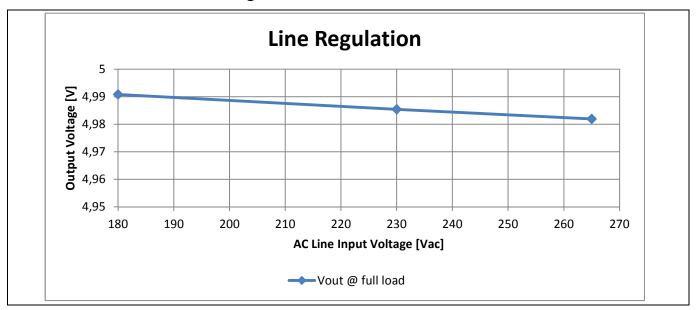


Figure 14 Power consumption versus input voltage when Pout=50 mW



#### Line and load regulation 9.4



Line regulation at full load Figure 15

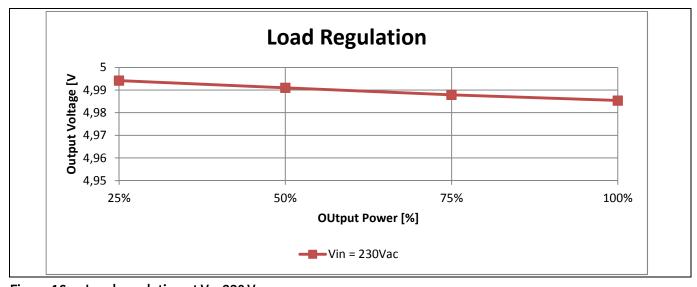


Figure 16 Load regulation at V<sub>in</sub>=230 V<sub>ac</sub>



## 9.5 Output voltage ripple

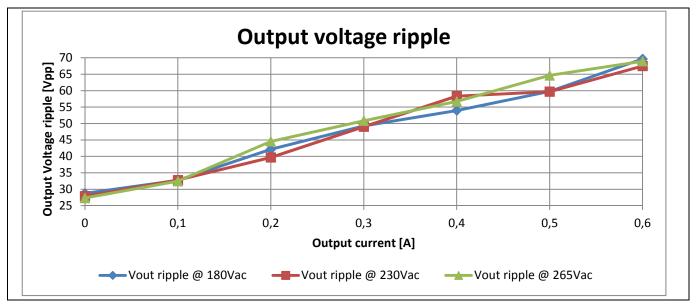


Figure 17 Output voltage ripple

Maximum output voltage ripple is 70 mVpp.

## 9.6 Thermal performance

The thermal photos were taken with a FLIR T600 thermal camera, after the board ran at full load for 45 minutes.

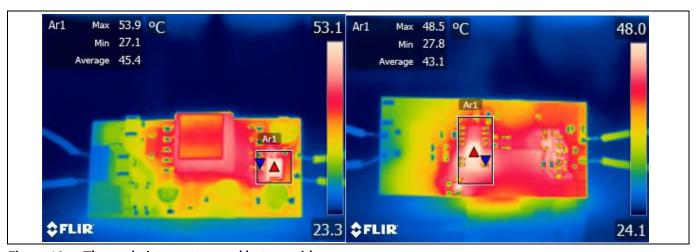


Figure 18 Thermal picture – top and bottom side

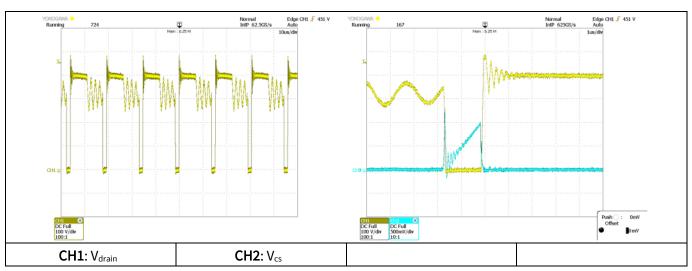
The hottest component is the diode D3, with a temperature of 54°C. The controller temperature is 49°C. Ambient temperature is 25°C.



**Waveforms** 

#### **Waveforms** 10

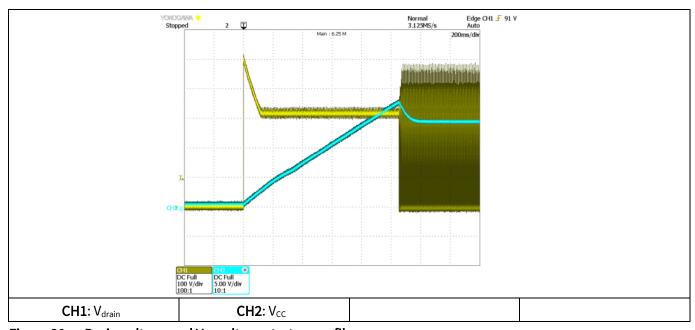
#### Switching waveforms at steady state 10.1



CoolMOS™ drain and source voltage waveforms @230 V<sub>ac</sub> and full load Figure 19

#### 10.2 Startup

Startup waveforms are captured @230  $V_{ac}$  and full load (resistive load).



Drain voltage and V<sub>cc</sub> voltage startup profile



Waveforms

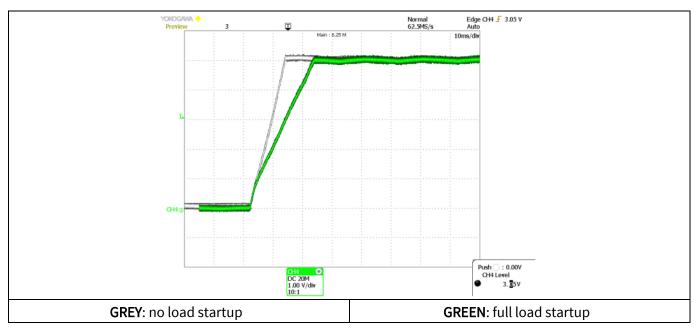
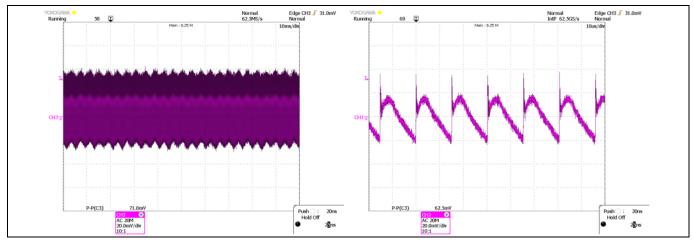


Figure 21 Output voltage startup profile

#### Output voltage ripple 10.3



Output voltage ripple @230 V<sub>ac</sub> and full load Figure 22



Waveforms

#### Active burst mode 10.4

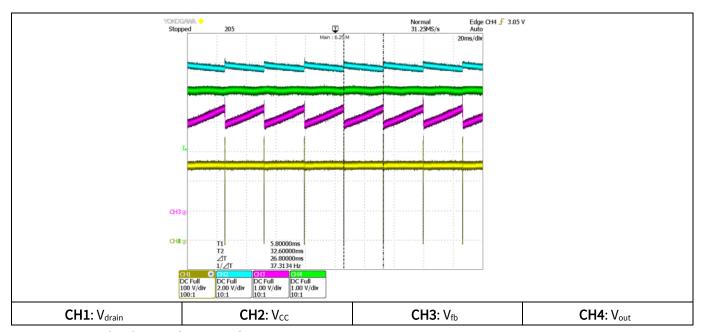
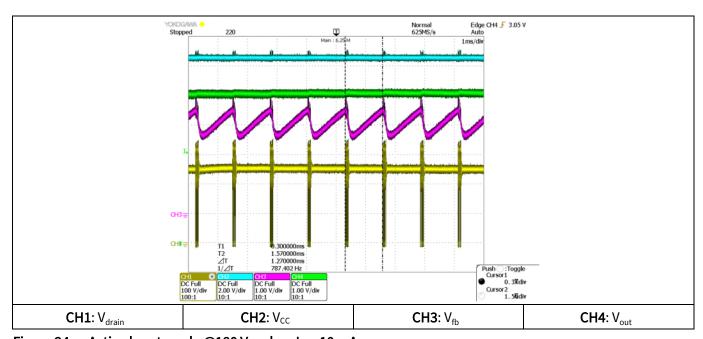


Figure 23 No load active burst mode @180 V<sub>ac</sub>



Active burst mode @180  $V_{ac}$  when  $I_{out}$ =10 mA Figure 24



Waveforms

## 10.5 Load transient response

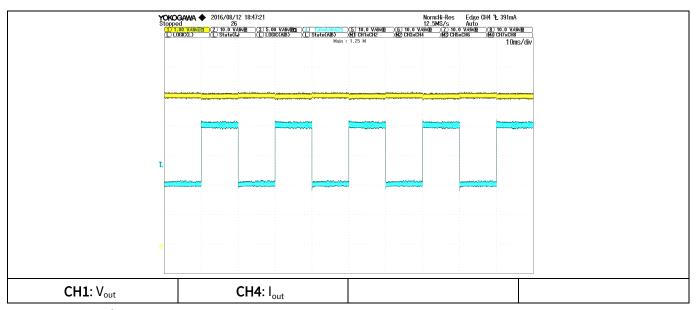


Figure 25 Load transient response

The load is switching between 50% and 100% with a 10 ms period. Slew rate is 0.2 A/ $\mu$ s.

## 10.6 Output voltage overshoot and undershoot

Test setup:  $V_{in}$  230 $V_{ac}$ ; E-load: Chroma 63103A, CC mode, slew rate 0.2 A/ $\mu$ s.

Figure 26 shows the  $V_{out}$  overshoot and undershoot when the load changes from full load to open load and vice versa. When the full load changes to open load, the  $V_{out}$  overshoot is 5.16 V. Vout undershoot is 4.81 V when the load jumps from open to full load.

NB: the waveforms in this section were measured with a YOKOGAWA DLM4058 Oscilloscope. Please refer to YOKOGAWA's user manual for the DC accuracy.

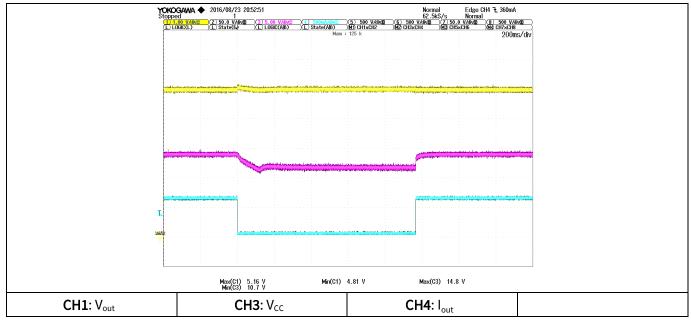


Figure 26 Output voltage overshoot and undershoot due to load transition



#### Waveforms

Some demo boards may demonstrate V<sub>out</sub> dual overshoots as shown in Figure 27. The first V<sub>out</sub> overshoot is due to the load jump from full load to open load. When the first V<sub>out</sub> overshoot happens, V<sub>FB</sub> is kept low and there is no PWM switching activity. Vout and Vcc start discharging. Vcc capacitor C7 and output capactiors C9 / C10 are Aluminum electrolytic capacitors with  $\pm 20\%$  capacitance tolerance. In extreme case, C7's tolerance is -20%, while both C9 and C10 have tolerance of +20%. V<sub>CC</sub> discharges (much) faster than V<sub>out</sub>, so that V<sub>CC</sub> triggers the UVLO (10.5V) before the IC enters active burst mode. Therefore, the IC enters auto restart. A second Vout overshoot happens when V<sub>cc</sub> is charged up to 18 V and the IC starts switching. The maximum V<sub>out</sub> is detected at the second overshoot: 5.23V.

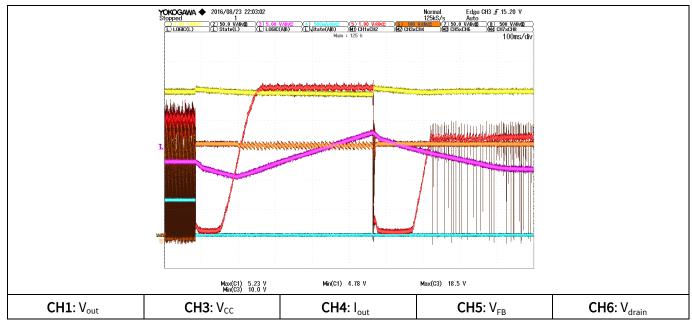
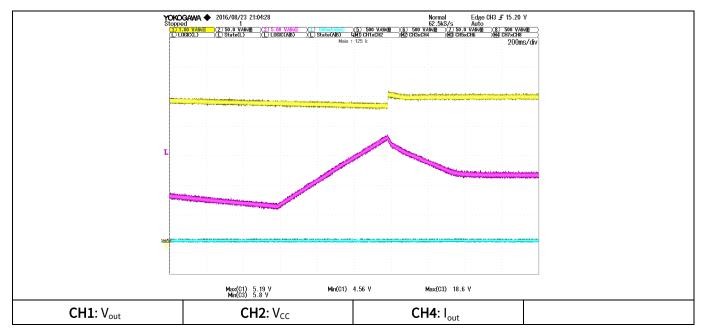


Figure 27 Output voltage dual overshoots due to load transition

Figure 28 and Figure 29 show the output voltage overshoot if a short AC line interruption occurs. With an open load, the overshoot is large as the device restarts and the startup procedure charges the output capacitors which are not yet discharged (CH4 V<sub>out</sub>). This overshoot can be reduced by making the feedback loop faster, but it will affect the power consumption at no load. V<sub>out</sub> overshoot level is 5.19 V.





**Waveforms** 

### Figure 28 Output voltage overshoot due to AC line voltage interruption (no load)

With a 10 mA load, when the AC source is removed,  $V_{out}$  ( $V_{out}$ ) discharges quickly to a low level. When the AC source is connected again, typically no overshoot was observed at  $V_{out}$ .

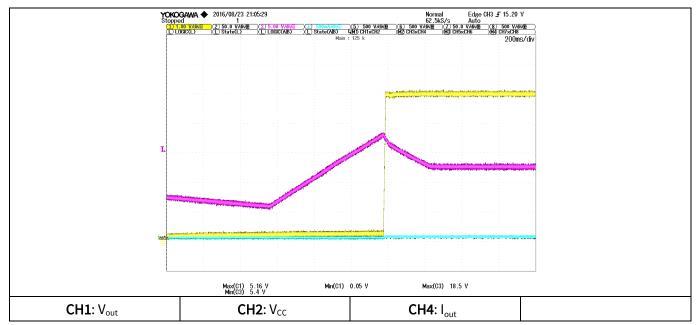


Figure 29 Output voltage overshoot due to AC line voltage interruption (I<sub>out</sub>=10 mA)

**Conducted EMI** 

#### 11 **Conducted EMI**

Conducted EMI was measured according to test standard EN55022 class B, at V<sub>in</sub>=230 V<sub>ac</sub> and full load.

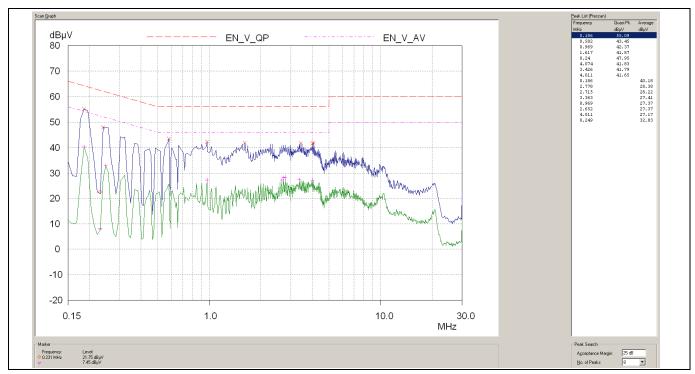


Figure 30 Line

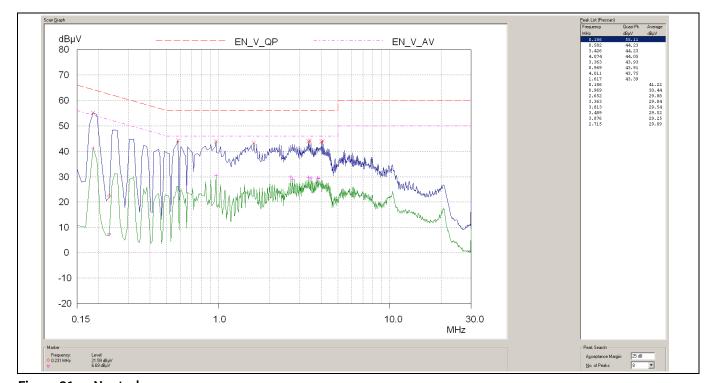


Figure 31 Neutral



References

#### References 12

- [1] Infineon Technologies, Datasheet ICE3RBR4765JG "Fixed-Frequency, 650 V CoolSET™ in DS0-12 Package"
- Infineon Technologies, Application Note 10 W 12 V SMPS Evaluation Board with CoolSET®-F3R ICE3BR4765JG



**Revision history** 

## **Revision history**

Major changes since the last revision

Page or Reference	Description of change
	First version

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